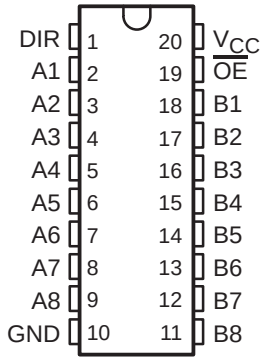
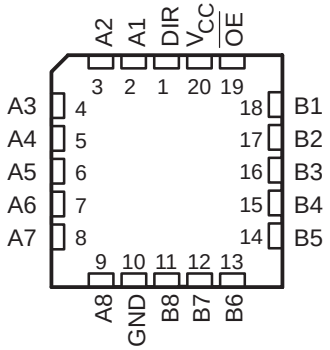
- **State-of-the-Art BiCMOS Design Substantially Reduces Standby Current**
- **Outputs Have Undershoot-Protection Circuitry**
- **Power-Up High-Impedance State**
- **Buffered Control Inputs to Reduce DC Loading Effects**
- **ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015**
- **Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK) and Flatpacks (W), and Plastic and Ceramic 300-mil DIPs (J, N)**

SN54BCT640 . . . J OR W PACKAGE
SN74BCT640 . . . DW OR N PACKAGE
(TOP VIEW)



SN54BCT640 . . . FK PACKAGE
(TOP VIEW)



description

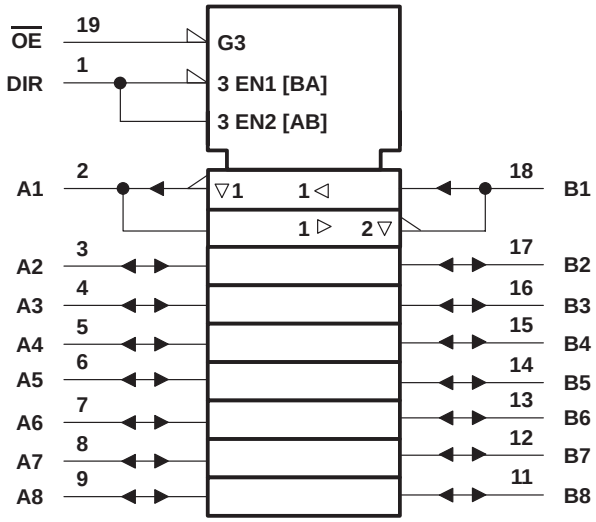
The ′BCT640 bus transceiver is designed for asynchronous communication between data buses. These devices transmit data from the A bus to the B bus or from the B bus to the A bus depending upon the level at the direction-control (DIR) input. The output-enable ($\overline{OE}$) input can be used to disable the device so that the buses are effectively isolated.

The SN54BCT640 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74BCT640 is characterized for operation from 0°C to 70°C.

FUNCTION TABLE

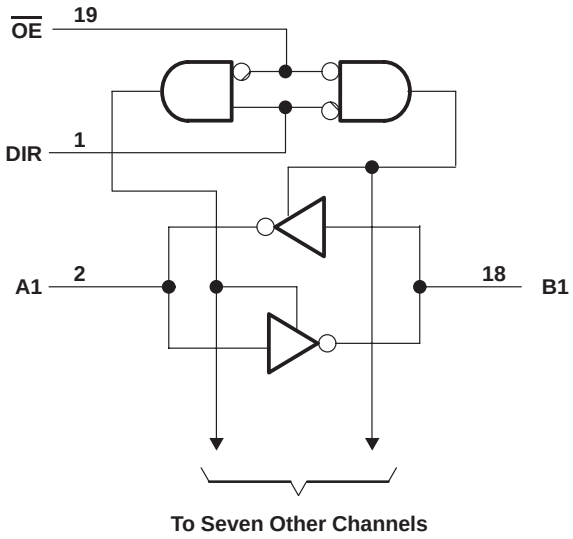
INPUTS		OPERATION
$\overline{OE}$	DIR	
L	L	$\overline{B}$ data to A bus
L	H	$\overline{A}$ data to B bus
H	X	Isolation

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V_{CC} . . . . . – 0.5 V to 7 V
Input voltage range: Control inputs (see Note 1) . . . . . – 0.5 V to 7 V
I/O ports (see Note 1) . . . . . – 0.5 V to 5.5 V
Voltage range applied to any output in the disabled or power-off state, V_O . . . . . – 0.5 V to 5.5 V
Voltage range applied to any output in the high state, V_O . . . . . – 0.5 V to V_{CC}
Input clamp current, I_{IK} . . . . . –30 mA
Current into any output in the low state: SN54BCT640 . . . . . 96 mA
SN74BCT640 . . . . . 128 mA
Operating free-air temperature range: SN54BCT640 . . . . . – 55°C to 125°C
SN74BCT640 . . . . . 0°C to 70°C
Storage temperature range . . . . . – 65°C to 150°C

‡ Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

recommended operating conditions

			SN54BCT640			SN74BCT640			UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	
V_{CC}	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
V_{IH}	High-level input voltage		2			2			V
V_{IL}	Low-level input voltage				0.8			0.8	V
I_{IK}	Input clamp current				–18			–18	mA
I_{OH}	High-level output current	A port			–3			–3	mA
		B port			–12			–15	
I_{OL}	Low-level output current	A port			20			24	mA
		B port			48			64	
T_A	Operating free-air temperature		–55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN54BCT640			SN74BCT640			UNIT
				MIN	TYP†	MAX	MIN	TYP†	MAX	
V_{IK}		V_{CC} = 4.5 V,	I_I = –18 mA			–1.2			–1.2	V
V_{OH}	A port	V_{CC} = 4.5 V	I_{OH} = –1 mA	2.5	3.4		2.5	3.4		V
			I_{OH} = –3 mA	2.4	3.3		2.4	3.3		
	B port	V_{CC} = 4.5 V	I_{OH} = –3 mA	2.4	3.3		2.4	3.3		
			I_{OH} = –12 mA	2	3.2					
			I_{OH} = –15 mA				2	3.1		
V_{OL}	A port	V_{CC} = 4.5 V	I_{OL} = 20 mA		0.3	0.5				V
			I_{OL} = 24 mA					0.35	0.5	
	B port	V_{CC} = 4.5 V	I_{OL} = 48 mA		0.38	0.55				
			I_{OL} = 64 mA					0.42	0.55	
I_I	A or B port	V_{CC} = 5.5 V,	V_I = 5.5 V			1			1	mA
	Control inputs					0.1			0.1	
I_{IH}‡	A or B port	V_{CC} = 5.5 V,	V_I = 2.7 V			70			70	µA
	Control inputs					20			20	
I_{IL}‡	A or B port	V_{CC} = 5.5 V,	V_I = 0.5 V			–0.6			–0.6	mA
	Control inputs					–0.65			–0.65	
I_{OS}§	A port	V_{CC} = 5.5 V,	V_O = 0	–60		–150	–60		–150	mA
	B port			–100		–225	–100		–225	
I_{CCL}	A to B	V_{CC} = 5.5 V			53	84		53	94	mA
I_{CCH}	A to B	V_{CC} = 5.5 V			23	37		23	41	mA
I_{CCZ}		V_{CC} = 5.5 V			4	10		4	11	mA

† All typical values are at V_{CC} = 5 V, T_A = 25°C.
‡ For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.
§ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

switching characteristics (see Note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 5 V, C_L = 50 pF, R1 = 500 Ω, R2 = 500 Ω, T_A = 25°C			V_{CC} = 4.5 V to 5.5 V, C_L = 50 pF, R1 = 500 Ω, R2 = 500 Ω, T_A = MIN to MAX†				UNIT
			′BCT640			SN54BCT640		SN74BCT640		
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A or B	B or A	0.5	3.6	5.6	0.5	7	0.5	6.5	ns
t_{PHL}			0.5	1.9	3.4	0.5	3.8	0.5	3.7	
t_{PZH}	$\overline{OE}$	A or B	3.1	6.4	8.9	2.6	10.5	2.6	10.2	ns
t_{PZL}			4.1	6.9	9.5	3.5	12.3	3.5	10.7	
t_{PHZ}	$\overline{OE}$	A or B	1.9	5	7.9	1.4	12.2	1.4	10.2	ns
t_{PLZ}			1.8	4.3	6.8	1.5	8.3	1.5	7.8	

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
NOTE 2: Load circuits and voltage waveforms are shown in Section 1.

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PRODUCT FOLDER | PRODUCT INFO: FEATURES | DESCRIPTION | DATASHEETS | PRICING/AVAILABILITY/PKG | SAMPLES | APPLICATION NOTES | RELATED DOCUMENTS | MODELS

PRODUCT SUPPORT: TRAINING

SN74BCT640, Octal Bus Transceivers

DEVICE STATUS: **ACTIVE**

PARAMETER NAME	SN54BCT640	SN74BCT640
Voltage Nodes (V)	5	5
Vcc range (V)	4.5 to 5.5	4.5 to 5.5
Input Level	TTL	TTL
Output Level	TTL	TTL
Output Drive (mA)		-15/64
No. of Outputs	8	8
Logic	Inv	Inv
Static Current		67.5
tpd max (ns)		6.5

FEATURES

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- State-of-the-Art BiCMOS Design Substantially Reduces Standby Current
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- Buffered Control Inputs to Reduce DC Loading Effects
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DESCRIPTION

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TECHNICAL DOCUMENTS

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To view the following documents, Acrobat Reader 4.0 is required.
To download a document to your hard drive, right-click on the link and choose 'Save'.

DATASHEET

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Full datasheet in Acrobat PDF: sn74bct640.pdf (77 KB,Rev.C) (Updated: 04/01/1994)

APPLICATION NOTES

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View Application Notes for Digital Logic

- Bus-Interface Devices With Output-Damping Resistors Or Reduced-Drive Outputs (Rev. A) (SCBA012A - Updated: 08/01/1997)
- Designing With Logic (Rev. C) (SDYA009C - Updated: 06/01/1997)
- Evaluation of Nickel/Palladium/Gold-Finished Surface-Mount Integrated Circuits (SZZA026 - Updated: 06/20/2001)
- Implications of Slow or Floating CMOS Inputs (Rev. C) (SCBA004C - Updated: 02/01/1998)
- Input and Output Characteristics of Digital Integrated Circuits (SDYA010 - Updated: 10/01/1996)
- LVT-to-LVTH Conversion (SCEA010 - Updated: 12/08/1998)
- Live Insertion (SDYA012 - Updated: 10/01/1996)
- Logic Solutions For IEEE Std 1284 (SCEA013 - Updated: 06/01/1999)

RELATED DOCUMENTS

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View Related Documentation for Digital Logic

- Logic Reference Guide (SCYB004, 1032 KB - Updated: 10/23/2001)
- Logic Selection Guide Second Half 2002 (Rev. R) (SDYU001R, 4274 KB - Updated: 07/19/2002)
- Military Semiconductors Selection Guide 2002 (Rev. B) (SGYC003B, 1648 KB - Updated: 04/22/2002)

SAMPLES

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ORDERABLE DEVICE	PACKAGE INDUSTRY (TI)	PINS	TEMP (°C)	STATUS	PRODUCT CONTENT	SAMPLES
SN74BCT640NSR	SOP (NS)	20		ACTIVE	View Product Content	Request Samples

PRICING/AVAILABILITY/PKG

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DEVICE INFORMATION							TI INVENTORY STATUS AS OF 3:00 PM GMT, 26 Sep 2002			REPORTED DISTRIBUTOR INVENTORY AS OF 3:00 PM GMT, 26 Sep 2002		
ORDERABLE DEVICE	STATUS	PACKAGE TYPE|PINS	TEMP (°C)	PRODUCT CONTENT	BUDGETARY PRICING QTY | $US	STD PACK QTY	IN STOCK	IN PROGRESS QTY|DATE	LEAD TIME	DISTRIBUTOR COMPANY|REGION	IN STOCK	PURCHASE
SN74BCT640DW	ACTIVE	SOP (DW) | 20	0 TO 70	View Contents	1KU | 1.68	25	N/A*	500 | 03 Oct	12 WKS			
								4629 | 04 Oct				
								>10k | 11 Oct				
SN74BCT640DWR	ACTIVE	SOP (DW) | 20	0 TO 70	View Contents	1KU | 1.71	2000	N/A*	4629 | 04 Oct	12 WKS			
								>10k | 11 Oct				
SN74BCT640N	ACTIVE	PDIP (N) | 20	0 TO 70	View Contents	1KU | 1.68	20	N/A*	19 | 23 Sep	12 WKS			
								4629 | 07 Oct				
								>10k | 14 Oct				
								>10k | 21 Oct				
SN74BCT640NSR	ACTIVE	SOP (NS) | 20		View Contents	1KU | 1.75	2000	N/A*	>10k | 14 Oct	12 WKS			

MODELS

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- IBIS Model of SN74BCT640 (SCBM045, 77 KB - Updated: 08/08/2000)
  IBIS Model of SN74BCT640 (SCBM045, 11 KB, ZIP - Updated: 08/08/2000)

Table Data Updated on: 9/26/2002